

Due Date: December 15, 2006

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:	Benjamin A. Haskell et al.	Examiner:	Steven Ho Yin Loke
Serial No.:	10/537,385	Group Art Unit:	2811
Filed:	June 3, 2005	Docket:	G&C 30794.94-US-WO
Title:	GROWTH OF PLANAR, NON-POLAR A-PLANE GALLIUM NITRIDE BY HYDRIDE VAPOR PHASE EPITAXY		

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

We are transmitting herewith the attached:

- ☒ Transmittal sheet.
- ☒ Information Disclosure Statement and Form PTO-1449.
- ☒ Cited Reference(s).

Please consider this a PETITION FOR EXTENSION OF TIME for a sufficient number of months to enter these papers, if appropriate.

Please charge all fees to Deposit Account No. 50-0494 of Gates & Cooper LLP.

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